

International  
**IR** Rectifier

ST700C..L SERIES

PHASE CONTROL THYRISTORS

Hockey Puk Version

#### Features

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case TO-200AC (B-PUK)

910A

#### Typical Applications

- DC motor control
- Controlled DC power supplies
- AC controllers

case style TO-200AC (B-PUK)

#### Major Ratings and Characteristics

Parameters	ST700C..L	Units
$I_{T(AV)}$	910	A
@ $T_{hs}$	55	°C
$I_{T(RMS)}$	1857	A
@ $T_{hs}$	25	°C
$I_{TSM}$	15700	A
@ 60Hz	16400	A
$I^2t$	1232	KA <sup>2</sup> s
@ 60Hz	1125	KA <sup>2</sup> s
$V_{DRM}/V_{RRM}$	1200 to 2000	V
$t_q$ typical	150	μs
$T_J$	- 40 to 125	°C

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Bulletin I25190 rev. D 04/00

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### ELECTRICAL SPECIFICATIONS

#### Voltage Ratings

Type number	Voltage Code	$V_{DRM}/V_{RRM}$ , max. repetitive peak and off-state voltage V	$V_{RSM}$ , maximum non-repetitive peak voltage V	$I_{DRM}/I_{RRM}$ max. @ $T_J = T_{J\max}$ mA
ST700C..L	12	1200	1300	80
	16	1600	1700	
	18	1800	1900	
	20	2000	2100	

#### On-state Conduction

Parameter	ST700C..L	Units	Conditions
$I_{T(AV)}$ Max. average on-state current @ Heatsink temperature	910 (355)	A	180° conduction, half sine wave
	55 (85)	°C	double side (single side) cooled
$I_{T(RMS)}$ Max. RMS on-state current	1857	A	DC @ 25°C heatsink temperature double side cooled
$I_{TSM}$ Max. peak, one-cycle non-repetitive surge current	15700		$t = 10\text{ms}$ No voltage reapplied
	16400		$t = 8.3\text{ms}$
	13200		$t = 10\text{ms}$ 100% $V_{RRM}$ reapplied
	13800		$t = 8.3\text{ms}$ reapplied
$I^2t$ Maximum $I^2t$ for fusing	1232	KA <sup>2</sup> s	Sinusoidal half wave, Initial $T_J = T_{J\max}$ .
	1125		
	871		
	795		
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	12321	KA <sup>2</sup> /s	$t = 0.1$ to 10ms, no voltage reapplied
$V_{T(TO)1}$ Low level value of threshold voltage	1.00	V	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_{J\max}$ .
$V_{T(TO)2}$ High level value of threshold voltage	1.13		$(I > \pi \times I_{T(AV)})$ , $T_J = T_{J\max}$ .
$r_{t1}$ Low level value of on-state slope resistance	0.40	mΩ	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_{J\max}$ .
$r_{t2}$ High level value of on-state slope resistance	0.35		$(I > \pi \times I_{T(AV)})$ , $T_J = T_{J\max}$ .
$V_{TM}$ Max. on-state voltage	1.80	V	$I_{pk} = 2000\text{A}$ , $T_J = T_{J\max}$ , $t_p = 10\text{ms}$ sine pulse
$I_H$ Maximum holding current	600	mA	$T_J = 25^\circ\text{C}$ , anode supply 12V resistive load
$I_L$ Typical latching current	1000		

Switching

Parameter	ST700C..L	Units	Conditions
di/dt	Max. non-repetitive rate of rise of turned-on current	1000	A/μs
$t_d$	Typical delay time	1.0	μs
$t_q$	Typical turn-off time	150	$I_{TM} = 750A, T_J = T_J \text{ max, } di/dt = 60A/\mu\text{s, } V_R = 50V$ $dv/dt = 20V/\mu\text{s, Gate } 0V \text{ to } 100\Omega, t_p = 500\mu\text{s}$

Blocking

Parameter	ST700C..L	Units	Conditions
dv/dt	Maximum critical rate of rise of off-state voltage	500	V/μs
$I_{DRM}$	Max. peak reverse and off-state leakage current	80	mA

Triggering

Parameter	ST700C..L	Units	Conditions
$P_{GM}$	Maximum peak gate power	10.0	
$P_{G(AV)}$	Maximum average gate power	2.0	
$I_{GM}$	Max. peak positive gate current	3.0	A
$+V_{GM}$	Maximum peak positive gate voltage	20	
$-V_{GM}$	Maximum peak negative gate voltage	5.0	V
$I_{GT}$	DC gate current required to trigger	TYP. 200 100 50	mA
$V_{GT}$	DC gate voltage required to trigger	MAX. - 2.5 1.8 1.1	V
$I_{GD}$	DC gate current not to trigger	10	mA
$V_{GD}$	DC gate voltage not to trigger	0.25	V

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### Thermal and Mechanical Specification

Parameter	ST700C..L	Units	Conditions
$T_J$	Max. operating temperature range	°C	
$T_{stg}$	Max. storage temperature range		
$R_{thJ-hs}$	Max. thermal resistance, junction to heatsink	K/W	DC operation single side cooled
	0.073 0.031		DC operation double side cooled
$R_{thC-hs}$	Max. thermal resistance, case to heatsink	K/W	DC operation single side cooled
	0.011 0.006		DC operation double side cooled
F	Mounting force, $\pm 10\%$	N (Kg)	
	14700 (1500)		
wt	Approximate weight	g	
Case style	TO - 200AC (B-PUK)	See Outline Table	

### $\Delta R_{thJ-hs}$ Conduction

(The following table shows the increment of thermal resistance  $R_{thJ-hs}$  when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.009	0.009	0.006	0.006	K/W	$T_J = T_{J \text{ max.}}$
120°	0.011	0.011	0.011	0.011		
90°	0.014	0.014	0.015	0.015		
60°	0.020	0.020	0.021	0.021		
30°	0.036	0.036	0.036	0.036		

### Ordering Information Table

Device Code									
1	ST	70	0	C	20	L	1		
		(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)
<b>1</b>	-	Thyristor							
<b>2</b>	-	Essential part number							
<b>3</b>	-	0 = Converter grade							
<b>4</b>	-	C = Ceramic Puk							
<b>5</b>	-	Voltage code: Code x 100 = $V_{RRM}$ (See Voltage Rating Table)							
<b>6</b>	-	L = Puk Case TO-200AC (B-PUK)							
<b>7</b>	-	0 = Eyelet terminals (Gate and Auxiliary Cathode Unsoldered Leads)							
		1 = Fast-on terminals (Gate and Auxiliary Cathode Unsoldered Leads)							
		2 = Eyelet terminals (Gate and Auxiliary Cathode Soldered Leads)							
		3 = Fast-on terminals (Gate and Auxiliary Cathode Soldered Leads)							
<b>8</b>	-	Critical dv/dt: None = 500V/ $\mu$ sec (Standard selection)							
		L = 1000V/ $\mu$ sec (Special selection)							

Outline Table

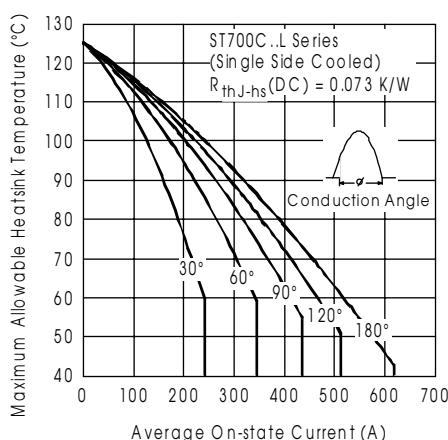
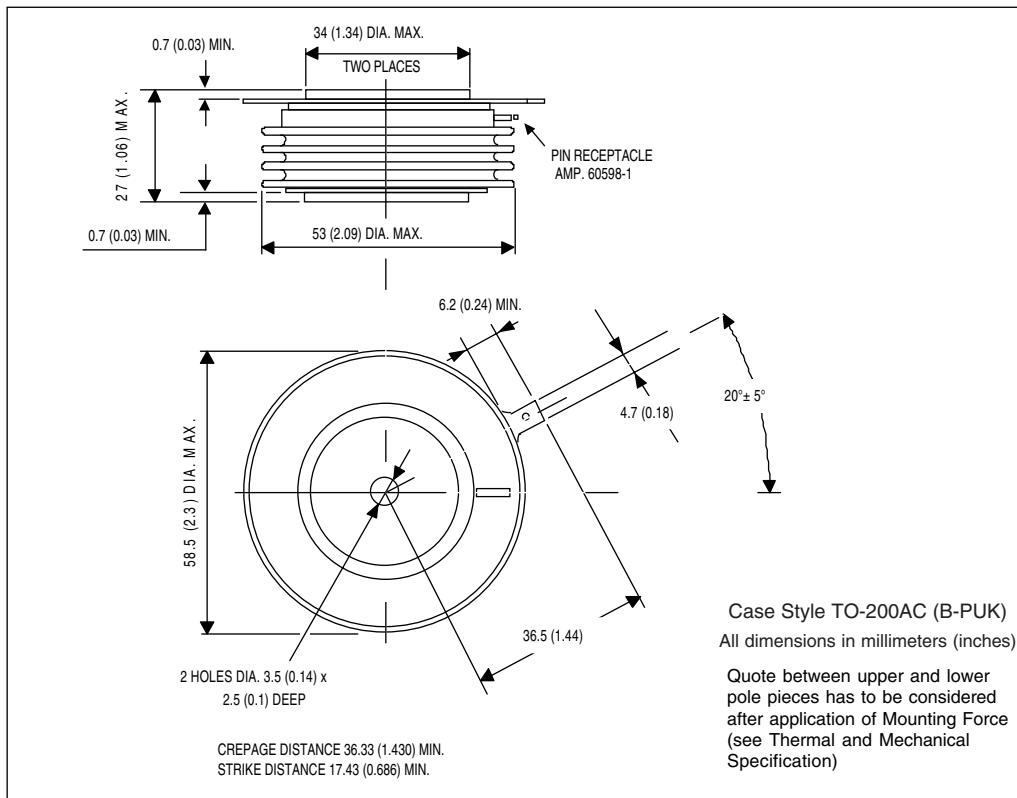


Fig. 1 - Current Ratings Characteristics

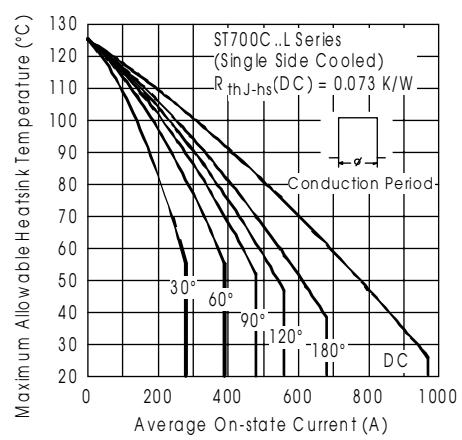


Fig. 2 - Current Ratings Characteristics

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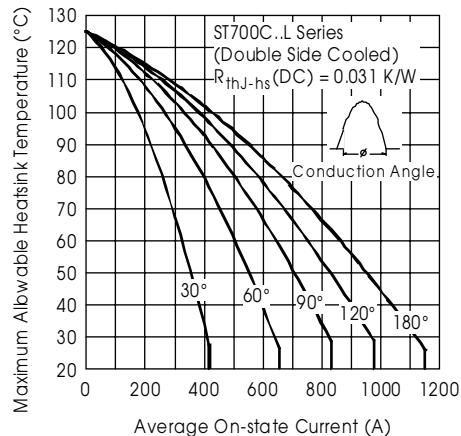


Fig. 3 - Current Ratings Characteristics

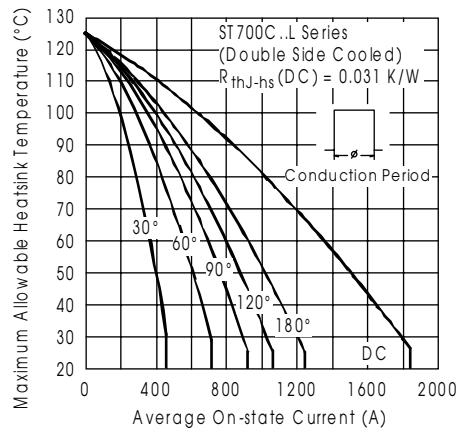


Fig. 4 - Current Ratings Characteristics

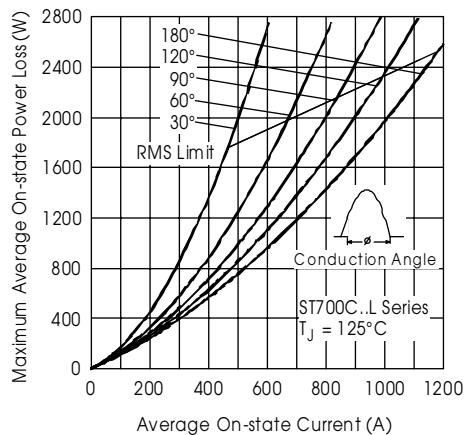


Fig. 5 - On-state Power Loss Characteristics

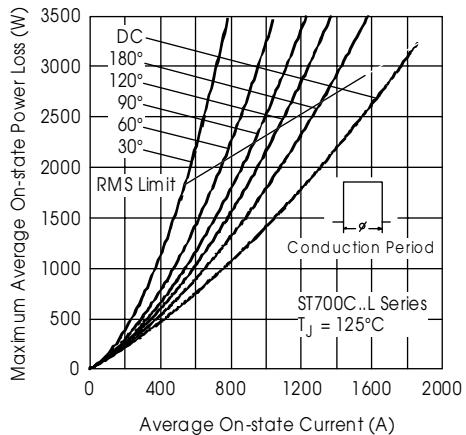


Fig. 6 - On-state Power Loss Characteristics

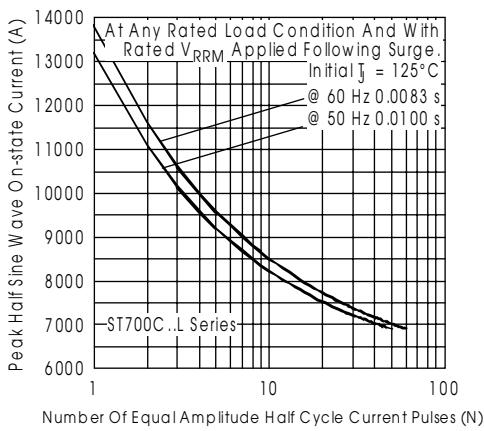


Fig. 7 - Maximum Non-Repetitive Surge Current  
Single and Double Side Cooled

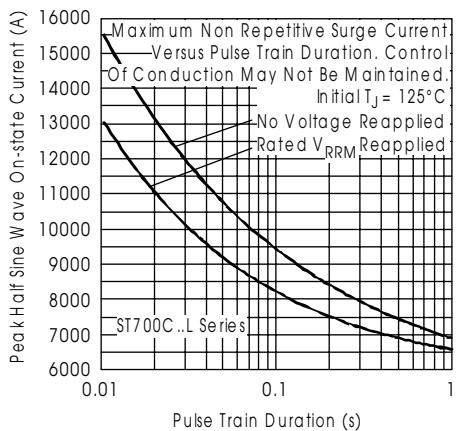


Fig. 8 - Maximum Non-Repetitive Surge Current  
Single and Double Side Cooled

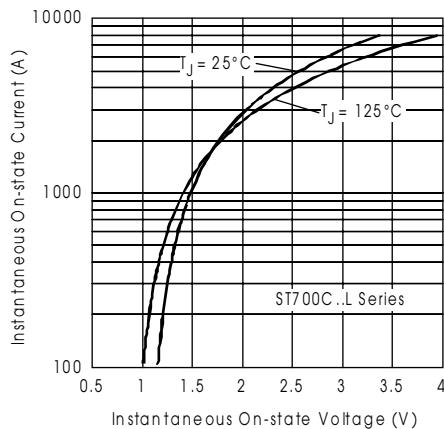


Fig. 9 - On-state Voltage Drop Characteristics

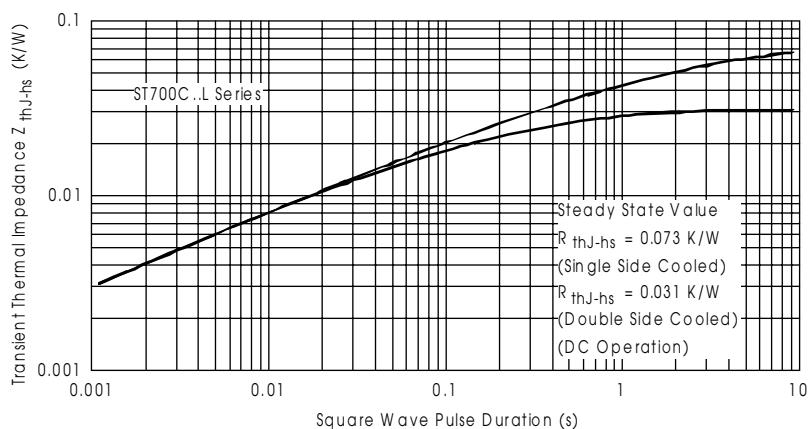


Fig. 10 - Thermal Impedance  $Z_{thJ-hs}$  Characteristics

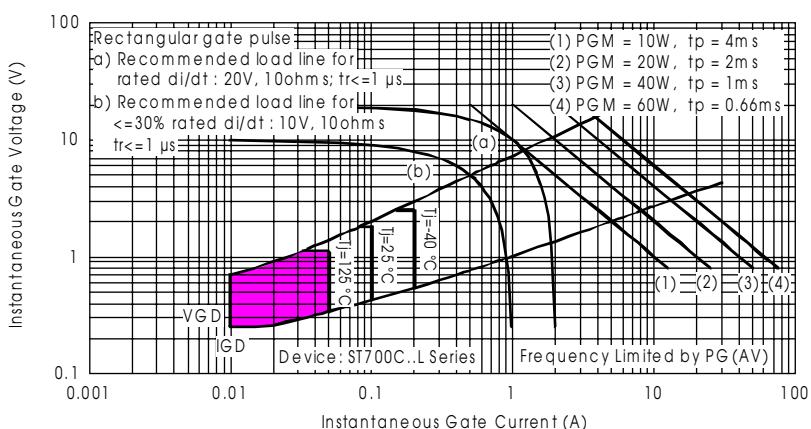


Fig. 11 - Gate Characteristics